

FAST: [09987660.wsp:1]

File View Edit Tools Window Help

☐ Drafts
☐ Pending
☒ Active
 L1: (3542) (257/79,86,96,101,103,190,615).CCL:
 L2: (1335) (438/22,37,933,936).CCLS
 L4: (34) 2 and concentration near5 (p near3 dopar
 L5: (4) 3 and(In near3 Ga near3 Al near N) or (Inx
 L6: (2) 4 and(In near3 Ga near3 Al near N) or (Inx
 L3 (80) 1 and concentration near5 (p near3 dopar
☐ Failed
 (0) "n type" with "p type"
☒ Saved
 (15163) "III-V"
 (0) "III-V" and nIn\$1Ga\$1Al\$1N
 (75) "III-V" and In\$1Ga\$1Al\$1N

Search:

DBs: USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM; TDB

Default operator: OR

☐ Plurals ☐ Highlight all hit terms initially

1 and concentration near5 (p near3 dopant\$)

	U	1	Document	Issue	Date	Page	Title	Current O	Current X	Retrieval	Inventor	S	C	P	2	3	
2	<input type="checkbox"/>	<input type="checkbox"/>	US 2003018	2003100	11		p-Type ohmic electrode i	257/79	257/94,		Lee, Jong Lam et al	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
3	<input type="checkbox"/>	<input type="checkbox"/>	US 2003015	2003081	15		Semiconductor light rece	257/79			Kawano, Kenji et al	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
4	<input type="checkbox"/>	<input type="checkbox"/>	US 2003013	2003071	8		Semiconductor optical d	257/14	257/101,		Hanamaki, Yoshihi	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
5	<input type="checkbox"/>	<input type="checkbox"/>	US 2003006	2003040	19		Semiconductor light emit	257/79	257/101,		Okazaki, Haruhiko	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
6	<input type="checkbox"/>	<input type="checkbox"/>	US 2002016	2002110	12		Semiconductor device an	257/102	257/103,		Northrup, John E. e	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
7	<input type="checkbox"/>	<input type="checkbox"/>	US 2002015	2002103	16		Semiconductor light-emit	257/79			Ono, Tomoki et al.	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
8	<input type="checkbox"/>	<input type="checkbox"/>	US 2002000	2002012	15		Formation of ohmic cont	257/79	257/E33.0		Goetz, Werner K. et	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
9	<input type="checkbox"/>	<input type="checkbox"/>	US 2001003	2001110	14		Nitride semiconductor de	372/45	257/101,		Takeuchi, Tetsuya e	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
10	<input type="checkbox"/>	<input type="checkbox"/>	US 2001003	2001110	16		Nitride semiconductor la	257/103			Ito, Shigetoshi et al	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
11	<input type="checkbox"/>	<input type="checkbox"/>	US 2001002	2001091	23		ALGAINP LIGHT EMIT	257/87	257/96,		GARDNER, NATH	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>
12	<input type="checkbox"/>	<input type="checkbox"/>	US 2001001	2001080	17		Semiconductor light emi	257/70	257/E33.0		Seaki, Ryu	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>	<input type="checkbox"/>

Ready

NUM